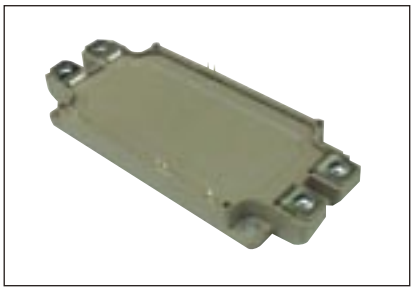
2MBI600VN-120-50

IGBT Modules

IGBT MODULE (V series)
1200V / 600A / 2 in one package

Features

High speed switching
Voltage drive
Low Inductance module structure



Applications

Inverter for Motor Drive
AC and DC Servo Drive Amplifier
Uninterruptible Power Supply
Industrial machines, such as Welding machines

Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units
Inverter	Collector-Emitter voltage	V_{CES}			1200	V
	Gate-Emitter voltage	V_{GES}			±20	V
	Collector current	Ic	Continuous	Tc=80°C	600	A
		Ic pulse	1ms	Tc=80°C	1200	
		-Ic			600	
		-Ic pulse	1ms		1200	
	Collector power dissipation	Pc	1 device		3750	W
Junction temperature		Tj			175	°C
Operating junction temperature (under switching conditions)		T_{jop}			150	
Case temperature		T_C			125	
Storage temperature		Tstg			-40 to +125	
Isolation voltage	between terminal and copper base (*1)	V_{iso}	AC : 1min.		2500	VAC
	between thermistor and others (*2)					
Screw torque	Mounting (*3)	-			3.5	N m
	Terminals (*4)				4.5	

Note *1: All terminals should be connected together during the test.
Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.
Note *3: Recommendable value : Mounting : 2.5-3.5 Nm (M5) Note *4: Recommendable value : Terminals : 3.5-4.5 Nm (M6)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

Items		Symbols	Conditions		Characteristics min.	Characteristics typ.	Characteristics max.	Units
Inverter	Zero gate voltage collector current	I_{CES}	V_{GE} = 0V, V_{CE} = 1200V		-	-	3.0	mA
	Gate-Emitter leakage current	I_{GES}	V_{CE} = 0V, V_{GE} = ±20V		-	-	600	nA
	Gate-Emitter threshold voltage	$V_{GE(th)}$	V_{CE} = 20V, I_C = 600mA		6.0	6.5	7.0	V
	Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	V_{GE} = 15V, I_C = 600A	Tj=25°C	-	2.65	3.10	V
				Tj=125°C	-	3.00	-	
				Tj=150°C	-	3.05	-	
		$V_{CE(sat)}$ (chip)		Tj=25°C	-	1.85	2.30	
				Tj=125°C	-	2.20	-	
				Tj=150°C	-	2.25	-	
	Input capacitance	Cies	V_{CE} = 10V, V_{GE} = 0V, f = 1MHz		-	48	-	nF
	Turn-on time	ton	V_{CC} = 600V, I_C = 600A, V_{GE} = ±15V, R_G = 0.62Ω		-	550	1200	nsec
		tr			-	180	600	
		tr (i)			-	120	-	
	Turn-off time	toff			-	1050	2000	
		tf			-	110	350	
	Forward on voltage	V_F (terminal)	V_{GE} = 0V, I_F = 600A	Tj=25°C	-	2.50	3.00	V
				Tj=125°C	-	2.65	-	
				Tj=150°C	-	2.60	-	
		V_F (chip)		Tj=25°C	-	1.70	2.15	
				Tj=125°C	-	1.85	-	
				Tj=150°C	-	1.80	-	
	Reverse recovery time	trr	I_F = 600A		-	200	600	nsec
Thermistor	Resistance	R	T=25°C		-	5000	-	Ω
			T=100°C		465	495	520	
	B value	B	T=25/50°C		3305	3375	3450	K

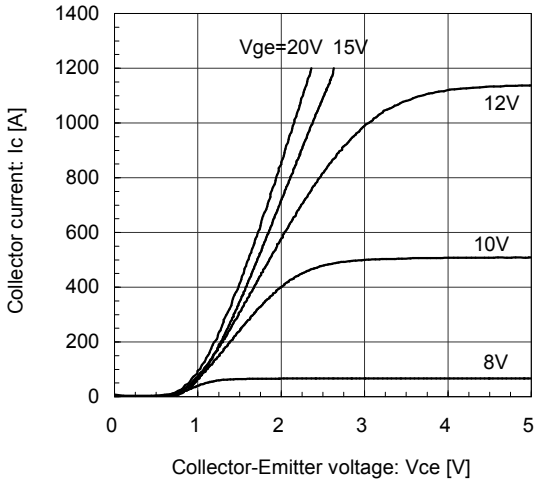
● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics min.	Characteristics typ.	Characteristics max.	Units
Thermal resistance (1device)	Rth(j-c)	Inverter IGBT	-	-	0.04	°C/W
		Inverter FWD	-	-	0.06	
Contact thermal resistance (1device) (*5)	Rth(c-f)	with Thermal Compound	-	0.0167	-	

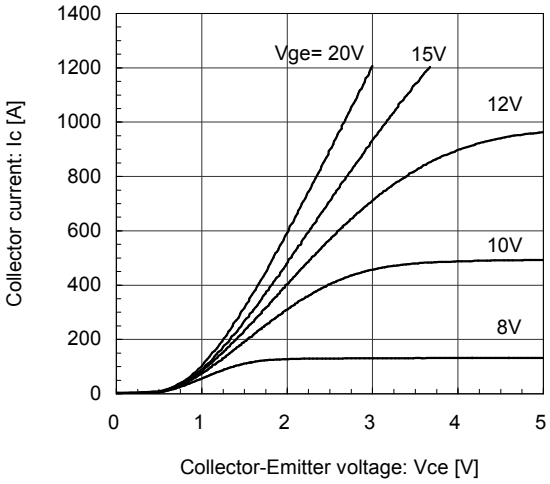
Note *5: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

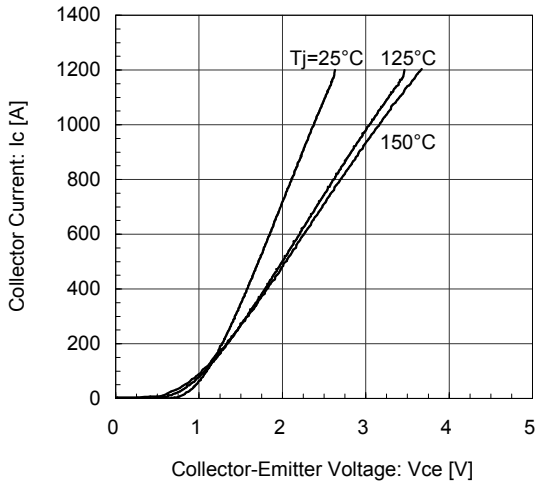
[INVERTER]
Collector current vs. Collector-Emitter voltage (typ.)
Tj= 25°C / chip



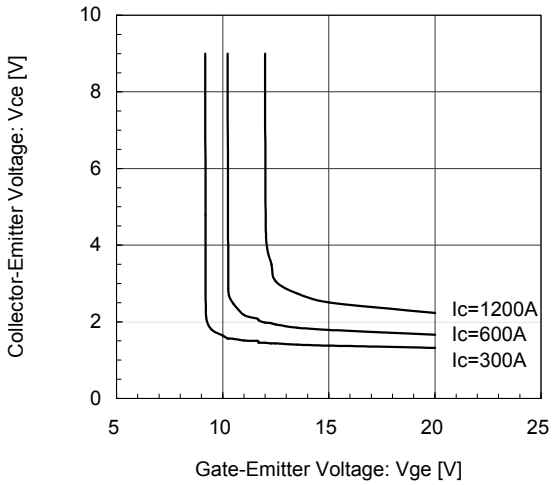
[INVERTER]
Collector current vs. Collector-Emitter voltage (typ.)
Tj= 150°C / chip



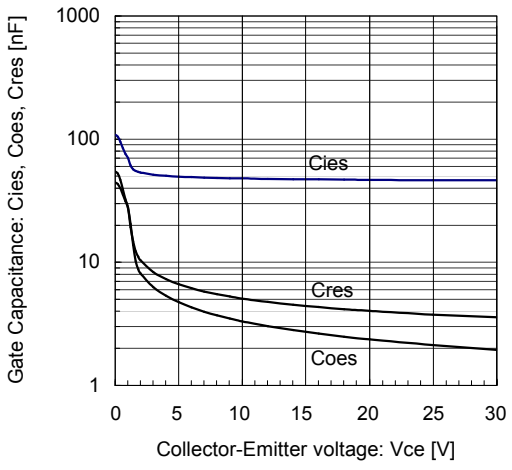
[INVERTER]
Collector current vs. Collector-Emitter voltage (typ.)
Vge= 15V / chip



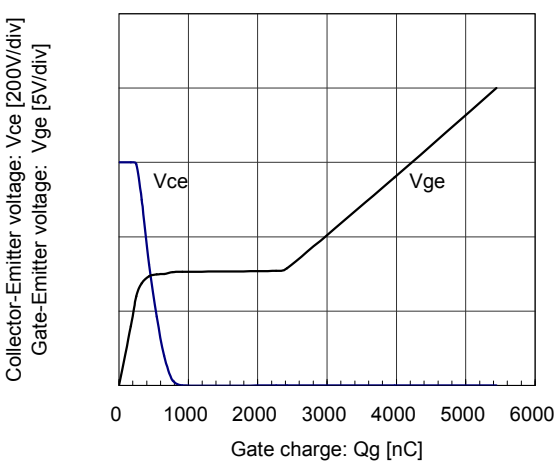
[INVERTER]
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.)
Tj= 25°C / chip



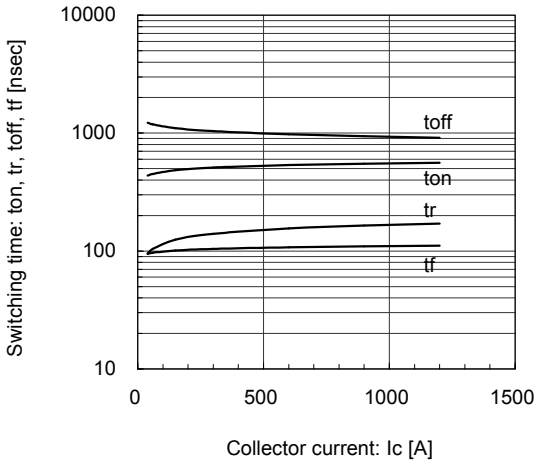
[INVERTER]
Gate Capacitance vs. Collector-Emitter Voltage (typ.)
Vge= 0V, f= 1MHz, Tj= 25°C



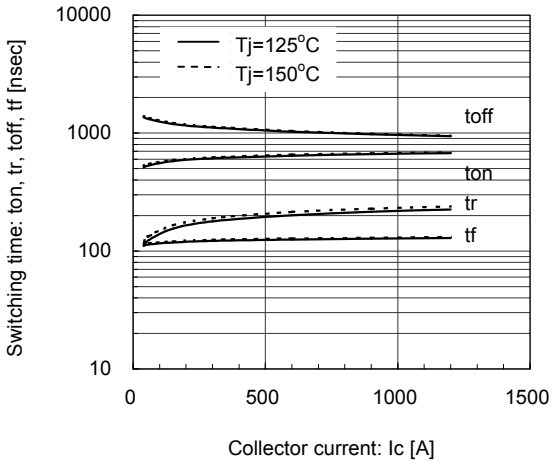
[INVERTER]
Dynamic Gate Charge (typ.)
Vcc=600V, Ic=600A, Tj= 25°C



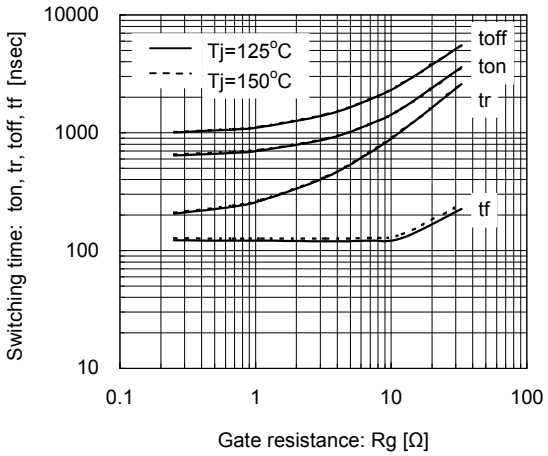
[INVERTER]
Switching time vs. Collector current (typ.)
Vcc=600V, Vge=±15V, Rg=0.62Ω, Tj=25°C



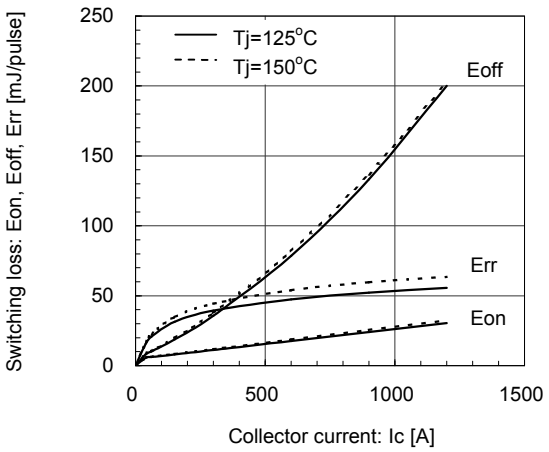
[INVERTER]
Switching time vs. Collector current (typ.)
Vcc=600V, Vge=±15V, Rg=0.62Ω, Tj=125°C, 150°C



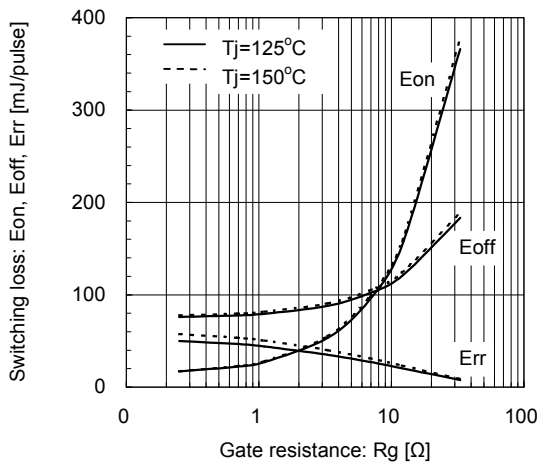
[INVERTER]
Switching time vs. Gate resistance (typ.)
Vcc=600V, Ic=600A, Vge=±15V, Tj=125°C, 150°C



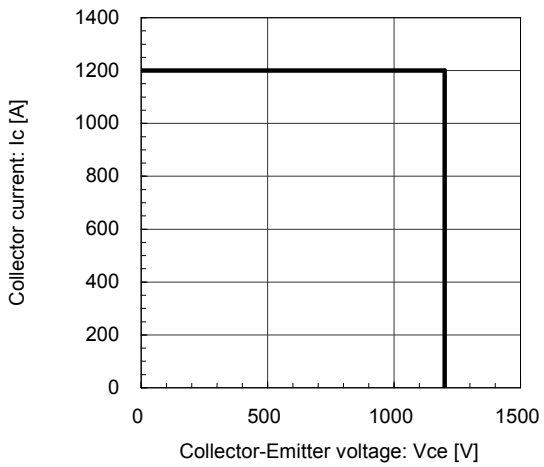
[INVERTER]
Switching loss vs. Collector current (typ.)
Vcc=600, Vge=±15V, Rg=0.62Ω, Tj=125°C, 150°C



[INVERTER]
Switching loss vs. Gate resistance (typ.)
Vcc=600V, Ic=600A, Vge=±15V, Tj=125°C, 150°C



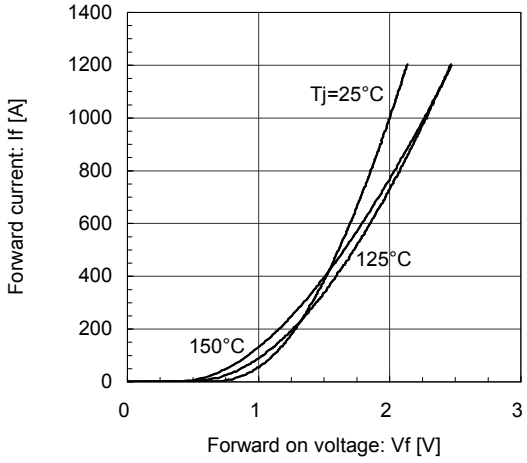
[INVERTER]
Reverse bias safe operating area (max.)
+Vge=15V, -Vge=15V, Rg=0.62Ω, Tj=150°C



[INVERTER]

Forward Current vs. Forward Voltage (typ.)

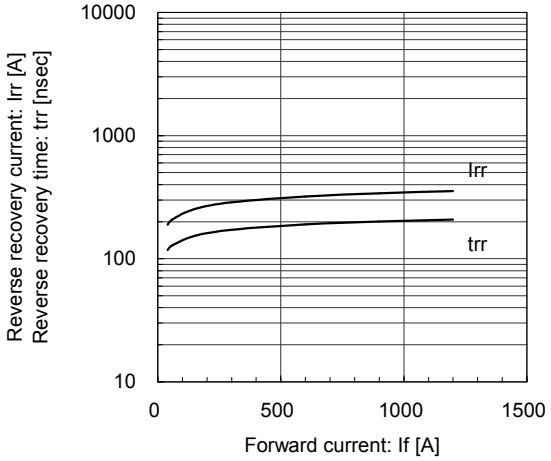
chip



[INVERTER]

Reverse Recovery Characteristics (typ.)

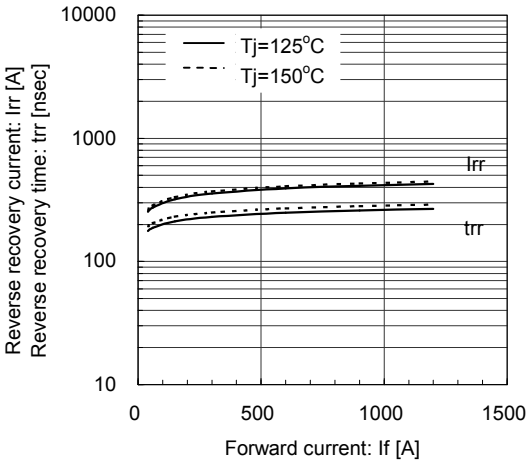
Vcc=600V, Vge=±15V, Rg=0.62Ω, Tj=25°C



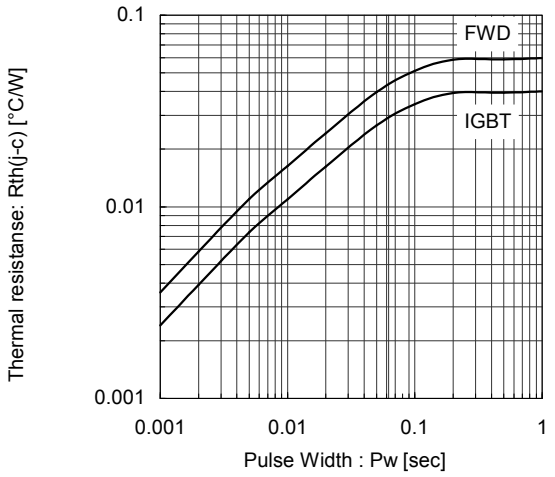
[INVERTER]

Reverse Recovery Characteristics (typ.)

Vcc=600V, Vge=±15V, Rg=0.62Ω, Tj=125°C, 150°C

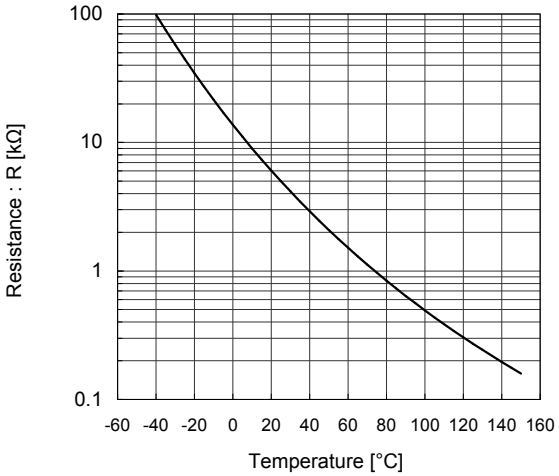


Transient Thermal Resistance (max.)

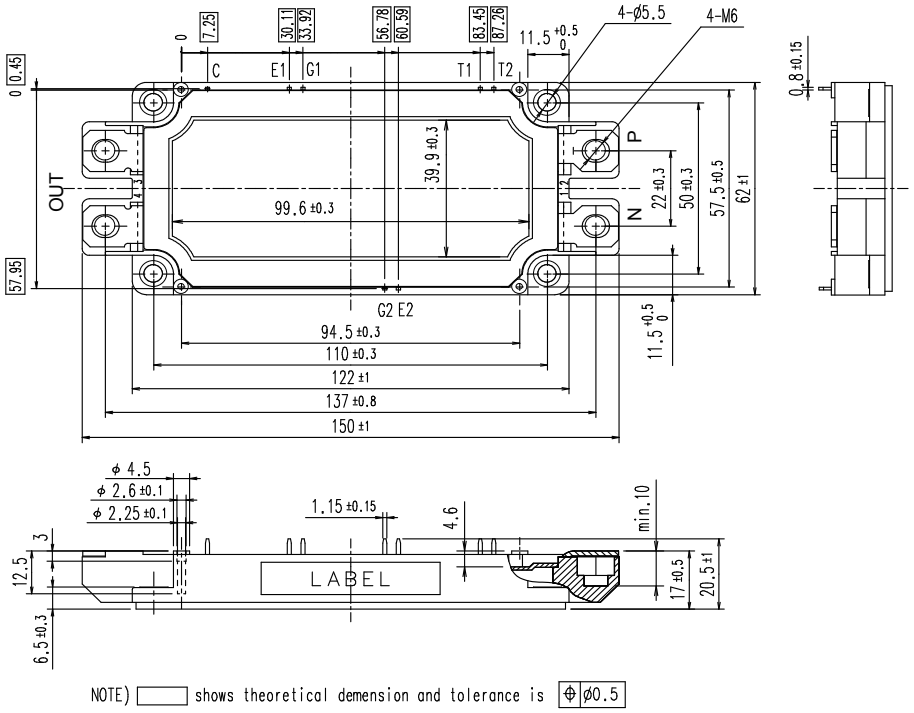


[THERMISTOR]

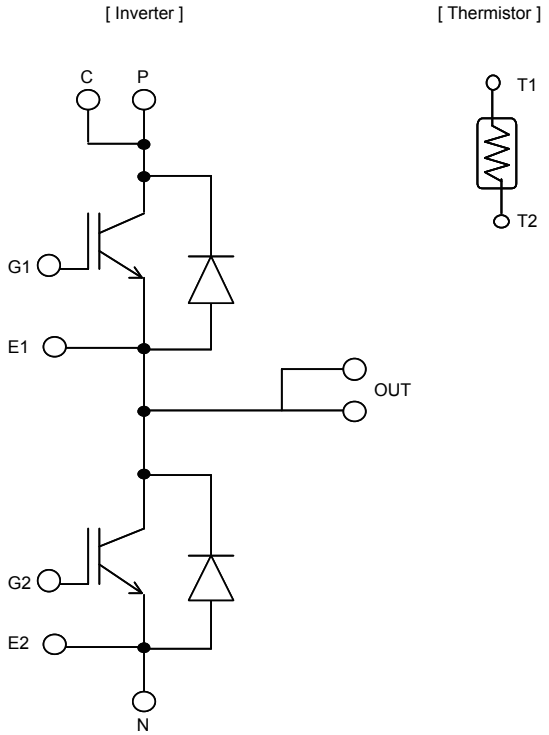
Temperature characteristic (typ.)



■ Outline Drawings, mm



■ Equivalent Circuit Schematic



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